

## **MGBR20U45C**

Preliminary

DIODE

# **DUAL MOS GATED BARRIER** RECTIFIER

### DESCRIPTION

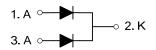
The UTC MGBR20U45C is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with high current capability, low forward voltage and high switching speed, etc.

#### **FEATURES**

\* Ultra low forward voltage

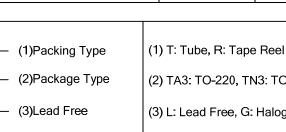
- \* High switching speed
- \* High current capability

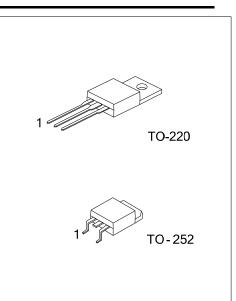
### SYMBOL



ORDERING INFORMATION								
Ordering Number		Deekege	Pin Assignment			Decking		
Lead Free	Halogen Free	Package	1	2	3	Packing		
MGBR20U45CL-TA3-T	MGBR20U45CG-TA3-T	TO-220	А	К	А	Tube		
MGBR20U45CL-TN3-T	MGBR20U45CG-TN3-T	TO-252	Α	К	Α	Tube		
MGBR20U45CL-TN3-T	MGBR20U45CG-TN3-T	TO-252	А	К	А	Tape Reel		

MGBR20U45CL-TA3-T	(1)Packing Type	(1) T: Tube, R: Tape Reel
	(2)Package Type	(2) TA3: TO-220, TN3: TO-252
	(3)Lead Free	(3) L: Lead Free, G: Halogen Free





## ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

For capacitance load, derate current by 20	<b>0</b> 70.			
PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V <sub>RM</sub>	45	V
Working Peak Reverse Voltage		V <sub>RWM</sub>	45	V
Peak Repetitive Reverse Voltage		V <sub>RRM</sub>	45	V
Average Rectified Forward Current (Rated VR-20KHz Square Wave) – 50% duty cycle	Per Leg	Io	10	А
	Total		20	А
Peak Forward Surge Current - 1/2 60Hz		I <sub>FSM</sub>	250	А
Peak Repetitive Reverse Surge Current (2	2µS-1KHz)	I <sub>RRM</sub>	2	А
Rate of Voltage Change ( at Rated $V_R$ )		dv/dt	10000	V/µS
Operating Junction Temperature		TJ	-65~+150	°C
Storage Temperature		T <sub>STG</sub>	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

## THERMAL DATA

PARAMETER	-	SYMBOL	RATINGS	UNIT	
lunction to Ambient	TO-220	0	62.5	°C 1.11	
Junction to Ambient	TO-252	θ <sub>JA</sub>	110	°C/W	
hunstien to Osea	TO-220	θ」с	2	°0444	
Junction to Case	TO-252		2.5	°C/W	

### ■ ELECTRICAL CHARACTERISTICS-(PER LEG) (T<sub>A</sub> =25°C unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	V <sub>(BR)R</sub>	I <sub>R</sub> =0.45mA	45			V
		I <sub>F</sub> =10A, TJ=25°C			0.43	V
Instantaneous Forward Voltage	$V_{FM}$	I <sub>F</sub> =10A, T <sub>J</sub> =125°C			0.40	V
Instantaneous Reverse Current (Note 1)		V <sub>R</sub> =45V, T <sub>J</sub> =25°C			500	μA
	I <sub>RM</sub>	V <sub>R</sub> =45V, T <sub>J</sub> =125°C			100	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

2. Thermal resistance junction to case mounted on heatsink.



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.

